NSN 5962-01-155-6153

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AeroBase

View Online at https://aerobasegroup.com/nsn/5962-01-155-6153

Body Length:	
0.840 inches	
Body Width:	
Between 0.220 inche	s and 0.310 inches
Body Height:	
Between 0.140 inche	s and 0.185 inches
Maximum Power Di	ssipation Rating:
739.0 milliwatts	
Operating Tempura	ture Range:
-55.0/+125.0 degree	s celsius
Storage Tempuratu	re Range:
-65.0/+150.0 degree	s celsius
Features Provided:	
Hermetically sealed a	and monolithic and positive outputs and schottky and programmable and programmed and bipolar and w/enable and
w/decoded output an	d w/buffered output
Inclosure Material:	
Ceramic and glass	
Inclosure Configura	ition:
Dual-in-line	
Output Logic Form	
Transistor-transistor	logic
Input Circuit Patter	1:
10 input	
Case Outline Sourc	e And Designator:
D-2 mil-m-38510	
Terminal Surface T	reatment:
Solder	
Voltage Rating And	Type Per Characteristic:
5.5 volts power sour	ce
Time Rating Per Ch	acteristic:
75.00 nanoseconds	propagation delay time, low to high level output and 75.00 nanoseconds propagation delay time, high to low level
output	
Memory Device Typ	e:
Rom	
Memory Capacity:	
Unknown	
Test Data Documen	t:
81349-mil-m-38510 s	specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes cor	nmercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and p	erformance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And	

Terminal Type And Quantity:

16 printed circuit

Shalf Life

Specification Data:

81349-mil-m-38510/203 government specification

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Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A458a0

